



General Description

The ELN8551, ELN8552 and ELN8554 are single, dual and quad amplifiers featuring rail-to-rail input and Output swings, which has ultralow offset, drift and bias current. All are guaranteed to operate from +2.7 V to +5 V Single supply. With an offset voltage of only 3 μ V and drift of 20 nV/ $^{\circ}$ C, the ELN8551 is perfectly suited for Applications where error sources cannot be tolerated. Temperature, position and pressure sensors, medical equipment and strain gage amplifiers benefit greatly from nearly zero drift over their operating temperature range. The rail-to-rail input and output swings provided by the ELN8551/358/324 family make both high-side and low-side sensing easy. The ELN8551/358/324 series is specified for the extended industrial/automotive (-40 $^{\circ}$ C to +125 $^{\circ}$ C) temperature range. The ELN8551 single is available in 5-lead SOT and 8-lead SOP/MSOP packages. The ELN8552 dual amplifier is available in 8-lead SOP/MSOP packages. The ELN8554 quad is available in narrow 14-lead SOP and 14-lead TSSOP packages.

Features

- ◆ Low Offset Voltage: 3 μ V (TYP)
- ◆ Rail-to-Rail Input and Output Swing
- ◆ 2.7V to 5.0V Single Supply Operation
- ◆ Voltage Gain: 145dB (TYP)
- ◆ PSRR: 115dB (TYP)
- ◆ CMRR: 110dB (TYP)
- ◆ Low Input Bias Currents: 130pA
- ◆ Low Supply Current: 450 μ A/Channel
- ◆ Overload Recovery Time: 0.1ms
- ◆ No External Capacitors Required
- ◆ -40 $^{\circ}$ C to +125 $^{\circ}$ C Operating Temperature Range
- ◆ Small Packaging:

ELN8551 Available in Green SOT23-5, SOP8 and MSOP8

ELN8552 Available in Green SOP8 and MSOP8

ELN8554 Available in Green SOP14 and TSSOP14

Applications

- ◆ Temperature Measurements
- ◆ Pressure Sensors
- ◆ Precision Current Sensing
- ◆ Electronic Scales
- ◆ Strain Gage Amplifiers
- ◆ Medical Instrumentation
- ◆ Thermocouple Amplifiers
- ◆ Handheld Test Equipment

Ordering/Marking Information

ELN8551NN
ELN8552NN XX X X
ELN8554NN

Package Type :

B2 : SOT23-5

M1 : SOP8

R1 : MSOP8

M2 : SOP14

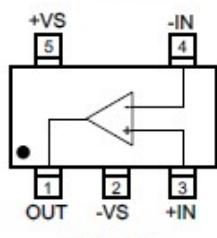
E1 : TSSOP14

R : Tape & Reel

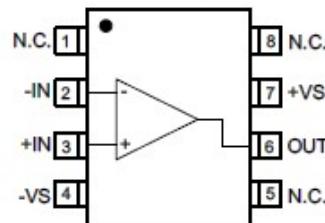
G : Green

Part Number	Package	Marking	Marking Information
ELN8551NNB2GR	SOT23-5	51AX	A、X: Tracking code
ELN8551NNM1GR	SOP8	LN8551 LLLL YYYYYY	LLLL : Process Code
ELN8551NNR1GR	MSOP8	LLLL YYYYYY	YYYYYY : Lot Code
ELN8552NNM1GR	SOP8	LN8552 LLLL YYYYYY	
ELN8552NNR1GR	MSOP8	LLLL YYYYYY	
ELN8554NNM2GR	SOP14	LN8554 LLLL YYYYYY	
ELN8554NNE1GR	TSSOP14	LLLL YYYYYY	

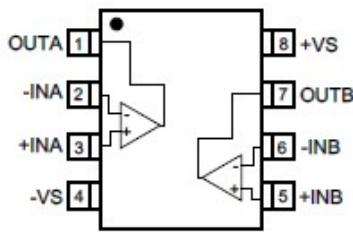
Package

ELN8551


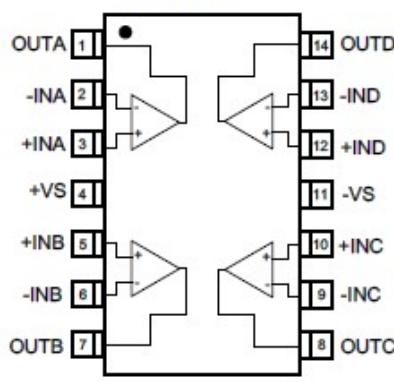
(SOT-23-5L)

ELN8551


(SOP-8/MSOP-8)

ELN8552


(SOP-8/MSOP-8)

ELN8554


(SSOP-14/TSSOP-8)



Zero-Drift, Single-Supply, Rail-to-Rail Input/Output Operational Amplifiers

ELN8551/8552/8554

Absolute Maximum Ratings

◆ Supply Voltage6V
◆ Input Voltage-VS+0.3V—+VS+0.3V
◆ Differential Input Voltage-5.0V to +5.0V
◆ Package Thermal Resistance @ TA = 25°C SOT23-5190°C/W
MSOP8216°C/W
SOP8125°C/W
SOP14120°C/W
TSSOP14180°C/W
◆ Storage temperature range-65°C to 150°C
◆ Operating junction temperature-40°C to 125°C
◆ ESD Human Model4000V
◆ Lead Temperature Range (Soldering 10 sec)260°C

Electrical Characteristics

VS = +5V, VCM = +2.5V, VO = +2.5V, TA = +25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
Vos	Input Offset Voltage		—	3	10	µV
I _B	Input Bias Current		100			pA
I _{os}	Input Offset Current		10			pA
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 5V	110			dB
A _{vo}	Large Signal Voltage Gain	R _L = 10kΩ V _O =0.3V~4.7V	145			dB
ΔV _{os} /Δ	Input Offset Voltage Drift		20			nV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	R _L = 100kΩ to -VS	4.99			V
		R _L = 10kΩ to -VS	4.99			V
V _{OL}	Output Voltage Low	R _L = 100kΩ to +VS	2			mV
		R _L = 10kΩ to +VS	5			mV
I _{sc}	Short Circuit Limit	R _L = 10Ω to -VS	43			mA
I _o	Output Current		30			mA
POWER SUPPLY						
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V	115			dB
I _Q	Quiescent Current	V _O = 0V, R _L = 0Ω	450			µA
DYNAMIC PERFORMANCE						
GBP	Gain-Bandwidth Product	G = +100	1.44			MHz
SR	Slew Rate	R _L = 10kΩ	0.84			V/µs
T _{OR}	Overload Recovery Time		0.10			ms
NOISE PERFORMANCE						
e _n p-p	Voltage Noise	0Hz to 10Hz	0.81			µVp-p
e _n	Voltage Noise Density	f = 1kHz	49			nV/ Hz



Zero-Drift, Single-Supply, Rail-to-Rail Input/Output Operational Amplifiers

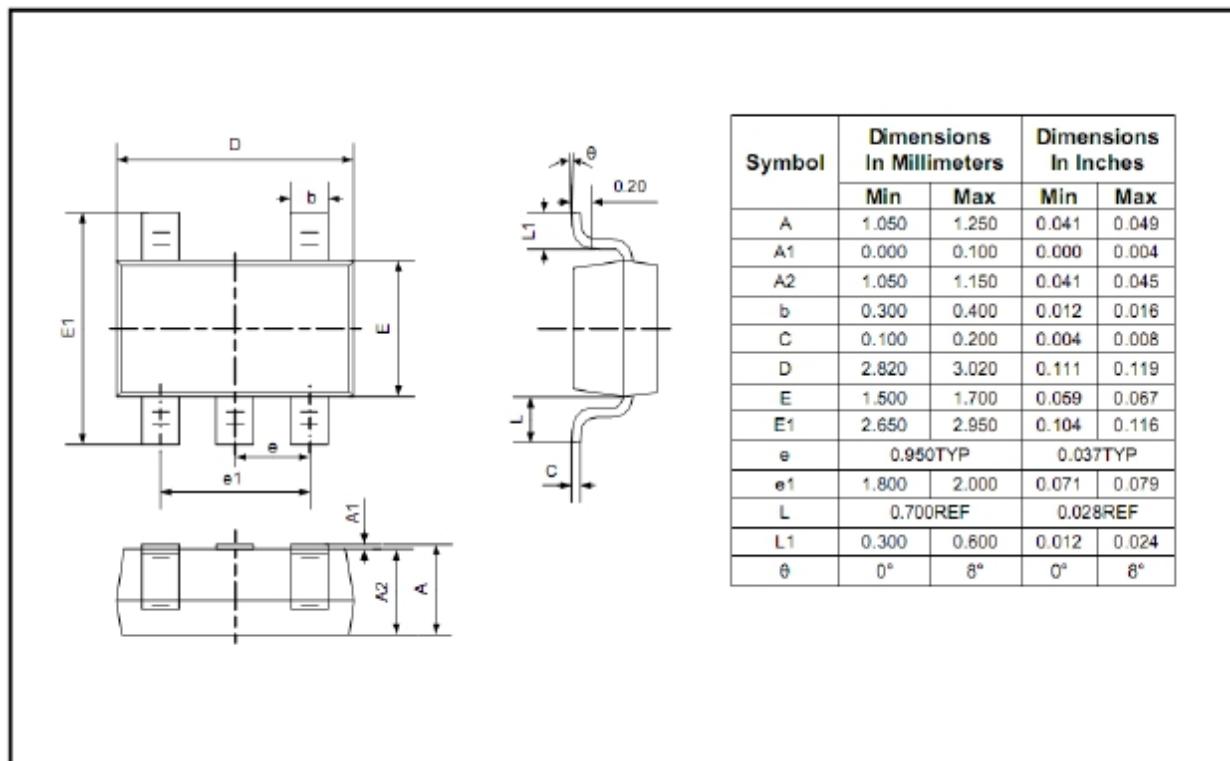
ELN8551/8552/8554

VS = +2.7V, VCM = +1.35V, VO = +1.35V, TA = +25°C, unless otherwise noted.

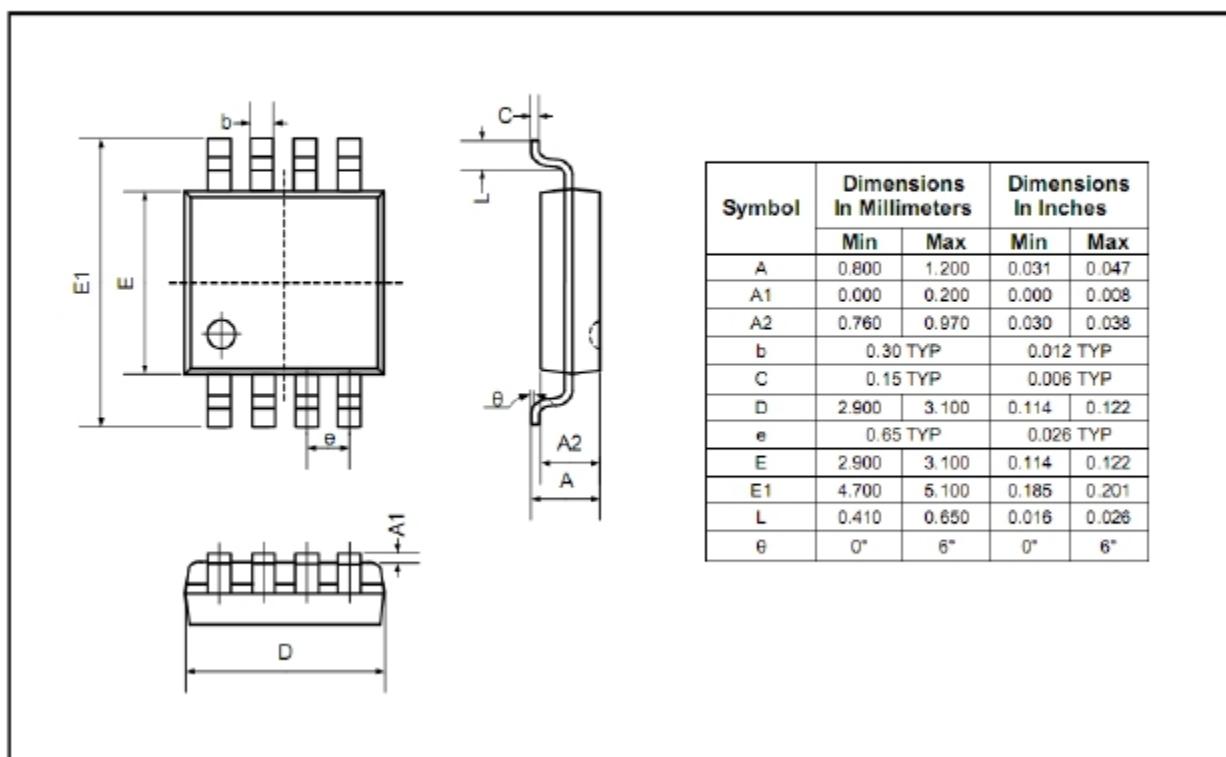
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{os}	Input Offset Voltage		—	3	10	μV
I _B	Input Bias Current		75			pA
I _{os}	Input Offset Current		5			pA
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 2.7V	110			dB
A _{vo}	Large Signal Voltage Gain	R _L = 10kΩ V _O =0.3V~2.4V	140			dB
ΔV _{os} /ΔT	Input Offset Voltage Drift		20			nV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	RL = 100kΩ to -VS		2.69		V
		RL = 10kΩ to -VS		2.69		V
V _{OL}	Output Voltage Low	RL = 100kΩ to +VS		1		mV
		RL = 10kΩ to +VS		2		mV
I _{sc}	Short Circuit Limit	RL = 10Ω to -VS		26		mA
I _o	Output Current			10		mA
POWER SUPPLY						
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V		115		dB
I _Q	Quiescent Current	V _O = 0V, R _L = 0Ω		450		μA
DYNAMIC PERFORMANCE						
GBP	Gain-Bandwidth Product	G = +100		1.43		MHz
SR	Slew Rate	RL = 10kΩ		0.84		V/μs
T _{OR}	Overload Recovery Time			0.04		ms
NOISE PERFORMANCE						
e _n p-p	Voltage Noise	0Hz to 10Hz		0.90		μVp-p
e _n	Voltage Noise Density	f = 1kHz		53		nV/ Hz

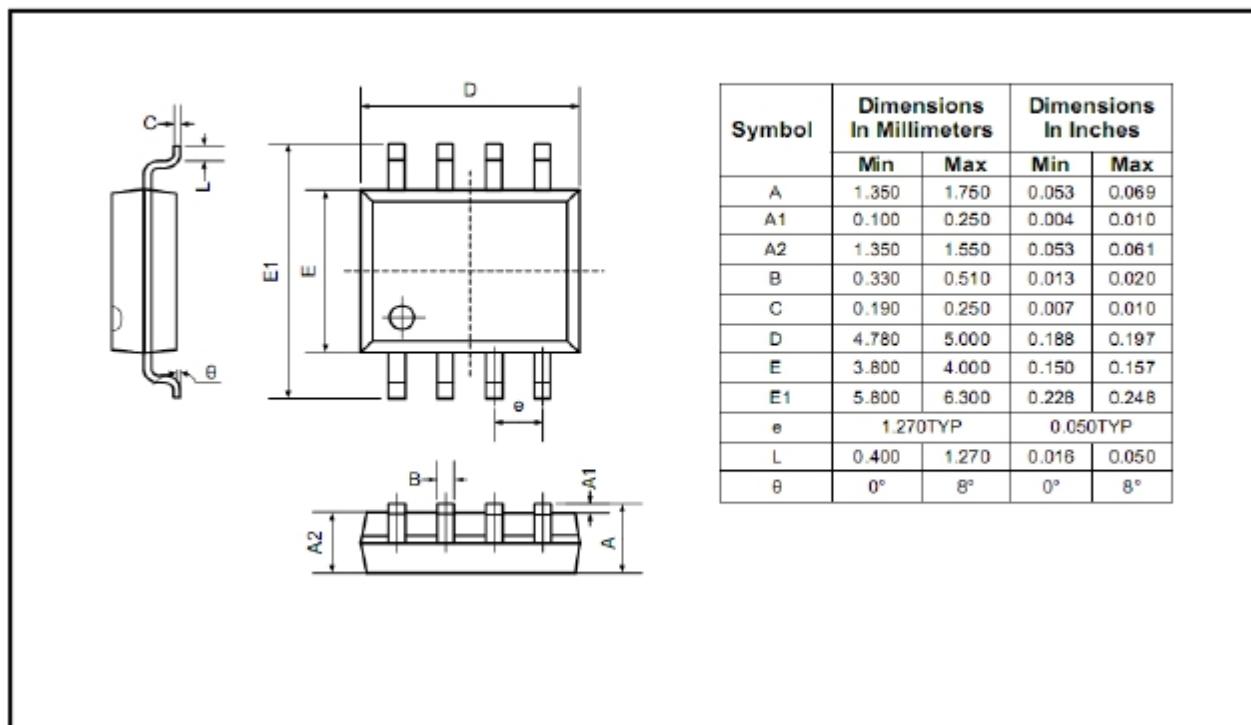
Package Information

SOT-23-5L



MSOP8



SOP8

SOP14
